

REMARKS

Initially, the courtesies extended by Examiner Im in conducting the telephonic interview on December 30, 2005, are greatly appreciated. During this interview, the following limitation of claim 1 was discussed,

wherein said semiconductor device is connected with said external electrodes via said first through-hole wiring and said internal wiring.

Specifically, Applicant's undersigned representative pointed out to Examiner Im that in order for this limitation to be read on Hung et al., assuming arguendo that conductive layer 216 is properly construed as ground electrodes, microstrip 112 must be connected with the first through-hole wiring 126 and the internal wiring 218. It was then explained why microstrip 112 is not connected with neither wiring 126 nor wiring 218, whereby semiconductor device 110 is not connected to ground electrodes or conductive layer 216 via the first through-hole wiring 126 and the internal wiring 218.

Specifically, Examiner Im's attention was directed to the initial paragraph in column 4 of Hung et al., which states that land region 106, within which is located microstrip 112, is "devoid of any conductive coating", and therefore, the microstrip cannot be connected with conductive layer 216 via the first through-hole wiring 126 and the internal wiring 218.

Examiner Im was in apparent agreement, and stated that were a response filed the current rejections of record would not be maintained if upon further consideration it is determined that the aforementioned limitation does indeed define around Hung et al.

Because in Hung et al., the microstrip 112 is not connected with either wiring 126 nor wiring 218, the semiconductor device 110 is not connected to conductive layer 216 via wiring 126 and wiring 218. Thus, claim 1 is not anticipated by Hung et al. Karnezos does not resolve this deficiency of Hung et al., and accordingly, claim 1 is also not obvious over a combination of Hung et al. and Karnezos, whereby claims 1-19 are allowable.

Also during this interview, Examiner Im indicated that Fig. 1 is inaccurate in that this figure apparently shows dielectric layers 13a and 13b to not be coextensive, whereas the remaining figures

do show such a coextensive relationship. Accordingly, a replacement formal drawing for Figure 1 is provided herewith, which shows dielectric layers 13a and 13b to be coextensive.

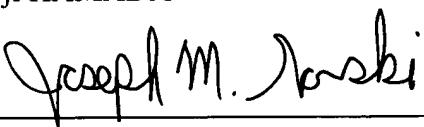
In view of the above, it is respectfully submitted that the application is in condition for allowance, and an early Notice of Allowance is earnestly solicited.

If after reviewing these remarks, the Examiner believes that any issues remain which must be resolved before the application can be passed to issue, the Examiner is invited to contact the Applicant's undersigned representative by telephone to resolve such issues.

Respectfully submitted,

Tomoji HAMADA

By:


Joseph M. Gorski
Registration No. 46,500
Attorney for Applicant

JMG/nka
Washington, D.C. 20006-1021
Telephone (202) 721-8200
Facsimile (202) 721-8250
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